Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.120 inches and 0.153 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.076 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Power Rating Per Characteristic:
125.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0